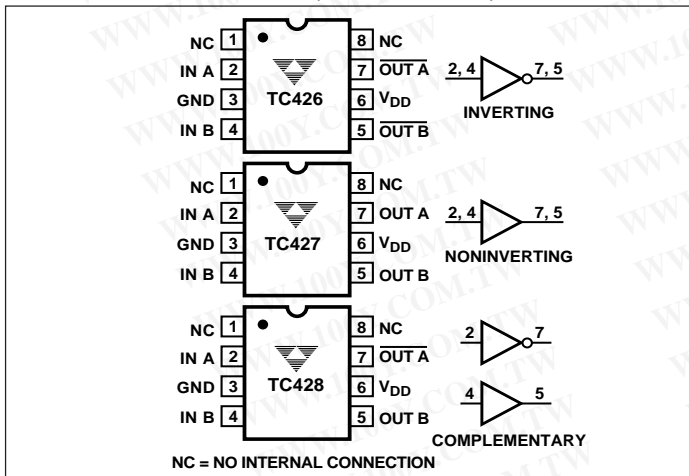


## 1.5A DUAL HIGH-SPEED POWER MOSFET DRIVERS

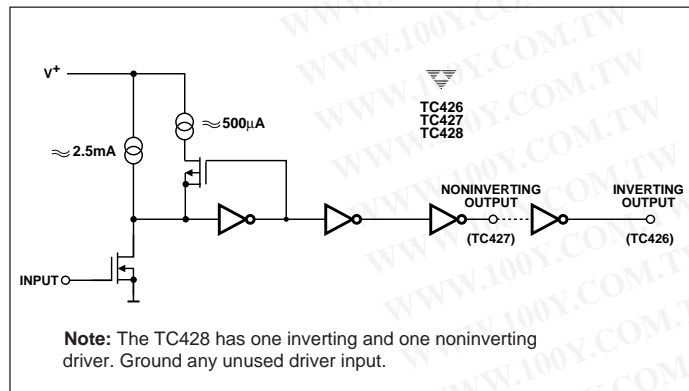
### FEATURES

- High-Speed Switching ( $C_L = 1000\text{pF}$ ) ..... 30nsec
- High Peak Output Current ..... 1.5A
- High Output Voltage Swing .....  $V_{DD} - 25\text{mV}$   
GND + 25mV
- Low Input Current (Logic "0" or "1") ..... 1 $\mu\text{A}$
- TTL/CMOS Input Compatible
- Available in Inverting and Noninverting Configurations
- Wide Operating Supply Voltage ..... 4.5V to 18V
- Current Consumption
  - Inputs Low ..... 0.4mA
  - Inputs High ..... 8mA
- Single Supply Operation
- Low Output Impedance ..... 6 $\Omega$
- Pinout Equivalent of DS0026 and MMH0026
- Latch-Up Resistant: Withstands > 500mA Reverse Current
- ESD Protected ..... 2kV

### PIN CONFIGURATIONS (DIP and SOIC)



### FUNCTIONAL BLOCK DIAGRAM



### GENERAL DESCRIPTION

The TC426/TC427/TC428 are dual CMOS high-speed drivers. A TTL/CMOS input voltage level is translated into a rail-to-rail output voltage level swing. The CMOS output is within 25 mV of ground or positive supply.

The low impedance, high-current driver outputs swing a 1000pF load 18V in 30nsec. The unique current and voltage drive qualities make the TC426/TC427/TC428 ideal power MOSFET drivers, line drivers, and DC-to-DC converter building blocks.

Input logic signals may equal the power supply voltage. Input current is a low 1 $\mu\text{A}$ , making direct interface to CMOS/bipolar switch-mode power supply control ICs possible, as well as open-collector analog comparators.

Quiescent power supply current is 8mA maximum. The TC426 requires 1/5 the current of the pin-compatible bipolar DS0026 device. This is important in DC-to-DC converter applications with power efficiency constraints and high-frequency switch-mode power supply applications. Quiescent current is typically 6mA when driving a 1000pF load 18V at 100kHz.

The inverting TC426 driver is pin-compatible with the bipolar DS0026 and MMH0026 devices. The TC427 is noninverting; the TC428 contains an inverting and noninverting driver.

Other pin compatible driver families are the TC1426/27/28, TC4426/27/28, and TC4426A/27A/28A.

### ORDERING INFORMATION

Part No.	Package	Configuration	Temperature Range
TC426COA	8-Pin SOIC	Inverting	0°C to +70°C
TC426CPA	8-Pin PDIP	Inverting	0°C to +70°C
TC426EOA	8-Pin SOIC	Inverting	-40°C to +85°C
TC426EPA	8-Pin SOIC	Complementary	-40°C to +85°C
TC426IJA	8-Pin CerDIP	Inverting	-25°C to +85°C
TC426MJA	8-Pin CerDIP	Inverting	-55°C to +125°C
TC427COA	8-Pin SOIC	Noninverting	0°C to +70°C
TC427CPA	8-Pin PDIP	Noninverting	0°C to +70°C
TC427EOA	8-Pin SOIC	Noninverting	-40°C to +85°C
TC427EPA	8-Pin SOIC	Complementary	-40°C to +85°C
TC427IJA	8-Pin CerDIP	Noninverting	-25°C to +85°C
TC427MJA	8-Pin CerDIP	Noninverting	-55°C to +125°C
TC428COA	8-Pin SOIC	Complementary	0°C to +70°C
TC428CPA	8-Pin PDIP	Complementary	0°C to +70°C
TC428EOA	8-Pin SOIC	Complementary	-40°C to +85°C
TC428EPA	8-Pin SOIC	Complementary	-40°C to +85°C
TC428IJA	8-Pin CerDIP	Complementary	-25°C to +85°C
TC428MJA	8-Pin CerDIP	Complementary	-55°C to +125°C

**TC426**  
**TC427**  
**TC428**

勝特力材料 886-3-5753170  
勝特力电子(上海) 86-21-54151736  
勝特力电子(深圳) 86-755-83298787  
Http://www.100y.com.tw

# 1.5A DUAL HIGH-SPEED POWER MOSFET DRIVERS

## ABSOLUTE MAXIMUM RATINGS\*

Supply Voltage .....	+20V
Input Voltage, Any Terminal ....	$V_{DD} + 0.3V$ to $GND - 0.3V$
Power Dissipation ( $T_A \leq 70^\circ C$ )	
Plastic .....	730mW
CerDIP .....	800mW
SOIC .....	470mW
Derating Factor	
Plastic .....	8mW/ $^\circ C$

CerDIP .....	6.4mW/ $^\circ C$
SOIC .....	4mW/ $^\circ C$
Operating Temperature Range	
C Version .....	$0^\circ C$ to $+70^\circ C$
I Version .....	$-25^\circ C$ to $+85^\circ C$
E Version .....	$-40^\circ C$ to $+85^\circ C$
M Version .....	$-55^\circ C$ to $+125^\circ C$
Maximum Chip Temperature .....	$+150^\circ C$
Storage Temperature Range .....	$-65^\circ C$ to $+150^\circ C$
Lead Temperature (Soldering, 10 sec) .....	$+300^\circ C$

## ELECTRICAL CHARACTERISTICS: $T_A = +25^\circ C$ with $4.5V \leq V_{DD} \leq 18V$ , unless otherwise specified.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
<b>Input</b>						
$V_{IH}$	Logic 1, High Input Voltage		2.4	—	—	V
$V_{IL}$	Logic 0, Low Input Voltage		—	—	0.8	V
$I_{IN}$	Input Current	$0V \leq V_{IN} \leq V_{DD}$	-1	—	1	$\mu A$
<b>Output</b>						
$V_{OH}$	High Output Voltage		$V_{DD} - 0.025$	—	—	V
$V_{OL}$	Low Output Voltage		—	—	0.025	V
$R_{OH}$	High Output Resistance	$I_{OUT} = 10\text{ mA}, V_{DD} = 18V$	—	10	15	$\Omega$
$R_{OL}$	Low Output Resistance	$I_{OUT} = 10\text{ mA}, V_{DD} = 18V$	—	6	10	$\Omega$
$I_{PK}$	Peak Output Current		—	1.5	—	A
<b>Switching Time (Note 1)</b>						
$t_R$	Rise Time	Test Figure 1/2	—	—	30	nsec
$t_F$	Fall Time	Test Figure 1/2	—	—	30	nsec
$t_{D1}$	Delay Time	Test Figure 1/2	—	—	50	nsec
$t_{D2}$	Delay Time	Test Figure 1/2	—	—	75	nsec
<b>Power Supply</b>						
$I_S$	Power Supply Current	$V_{IN} = 3V$ (Both Inputs) $V_{IN} = 0V$ (Both Inputs)	— —	— —	8 0.4	$\text{mA}$ $\text{mA}$

## ELECTRICAL CHARACTERISTICS: Over Operating Temperature Range with $4.5V \leq V_{DD} \leq 18V$ , unless otherwise specified.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
<b>Input</b>						
$V_{IH}$	Logic 1, High Input Voltage		2.4	—	—	V
$V_{IL}$	Logic 0, Low Input Voltage		—	—	0.8	V
$I_{IN}$	Input Current	$0V \leq V_{IN} \leq V_{DD}$	-10	—	10	$\mu A$
<b>Output</b>						
$V_{OH}$	High Output Voltage		$V_{DD} - 0.025$	—	—	V
$V_{OL}$	Low Output Voltage		—	—	0.025	V
$R_{OH}$	High Output Resistance	$I_{OUT} = 10\text{ mA}, V_{DD} = 18V$	—	13	20	$\Omega$
$R_{OL}$	Low Output Resistance	$I_{OUT} = 10\text{ mA}, V_{DD} = 18V$	—	8	15	$\Omega$
<b>Switching Time (Note 1)</b>						
$t_R$	Rise Time	Test Figure 1/2	—	—	60	nsec
$t_F$	Fall Time	Test Figure 1/2	—	—	30	nsec
$t_{D1}$	Delay Time	Test Figure 1/2	—	—	75	nsec
$t_{D2}$	Delay Time	Test Figure 1/2	—	—	120	nsec
<b>Power Supply</b>						
$I_S$	Power Supply Current	$V_{IN} = 3V$ (Both Inputs) $V_{IN} = 0V$ (Both Inputs)	— —	— —	12 0.6	$\text{mA}$ $\text{mA}$

NOTE: 1. Switching times guaranteed by design.

# 1.5A DUAL HIGH-SPEED POWER MOSFET DRIVERS

勝特力材料 886-3-5753170  
勝特力电子(上海) 86-21-54151736  
勝特力电子(深圳) 86-755-83298787  
Http://www.100y.com.tw

TC426  
TC427  
TC428

\*Static-sensitive device. Unused devices must be stored in conductive material. Protect devices from static discharge and static fields. Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional

operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may effect device reliability.

## SUPPLY BYPASSING

Charging and discharging large capacitive loads quickly requires large currents. For example, charging a 1000-pF load to 18V in 25nsec requires an 0.72A current from the device power supply.

To guarantee low supply impedance over a wide frequency range, a parallel capacitor combination is recommended for supply bypassing. Low-inductance ceramic disk capacitors with short lead lengths (< 0.5 in.) should be used. A 1  $\mu$ F film capacitor in parallel with one or two 0.1  $\mu$ F ceramic disk capacitors normally provides adequate bypassing.

## GROUNDING

The TC426 and TC428 contain inverting drivers. Ground potential drops developed in common ground impedances from input to output will appear as negative feedback and degrade switching speed characteristics.

Individual ground returns for the input and output circuits or a ground plane should be used.

## INPUT STAGE

The input voltage level changes the no-load or quiescent supply current. The N-channel MOSFET input stage transistor drives a 2.5mA current source load. With a logic "1" input, the maximum quiescent supply current is 8 mA. Logic "0" input level signals reduce quiescent current to 0.4 mA maximum. Minimum power dissipation occurs for logic "0" inputs for the TC426/427/428. **Unused driver inputs must be connected to  $V_{DD}$  or GND.**

The drivers are designed with 100 mV of hysteresis. This provides clean transitions and minimizes output stage current spiking when changing states. Input voltage thresholds are approximately 1.5V, making the device TTL compatible over the 4.5V to 18V supply operating range. Input current is less than 1  $\mu$ A over this range.

The TC426/427/428 may be directly driven by the TL494, SG1526/1527, SG1524, SE5560, and similar switch-mode power supply integrated circuits.

## POWER DISSIPATION

The supply current vs frequency and supply current vs capacitive load characteristic curves will aid in determining power dissipation calculations.

The TC426/427/428 CMOS drivers have greatly reduced quiescent DC power consumption. Maximum quiescent current is 8 mA compared to the DS0026 40 mA specification. For a 15V supply, power dissipation is typically 40 mW.

Two other power dissipation components are:

- Output stage AC and DC load power.
- Transition state power.

Output stage power is:

$$P_o = P_{DC} + P_{AC} \\ = V_o (I_{DC}) + f C_L V_s$$

Where:

- $V_o$  = DC output voltage
- $I_{DC}$  = DC output load current
- $f$  = Switching frequency
- $V_s$  = Supply voltage

In power MOSFET drive applications the  $P_{DC}$  term is negligible. MOSFET power transistors are high impedance, capacitive input devices. In applications where resistive loads or relays are driven, the  $P_{DC}$  component will normally dominate.

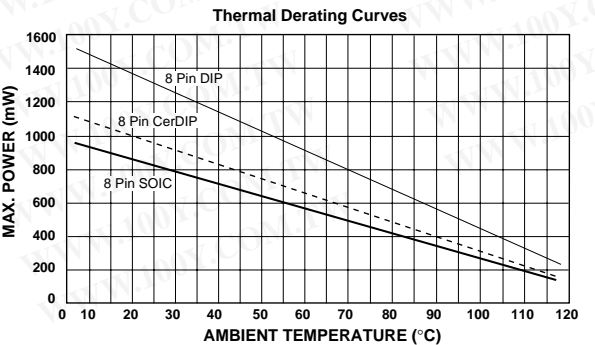
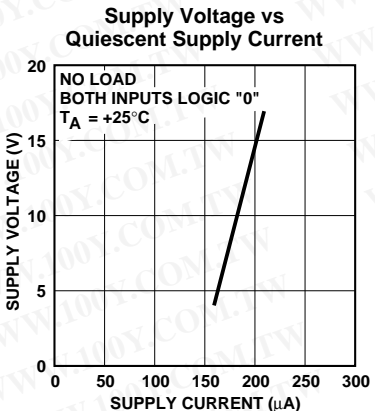
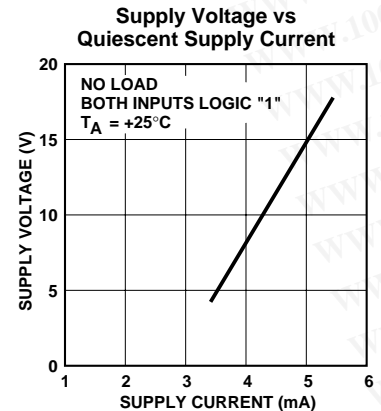
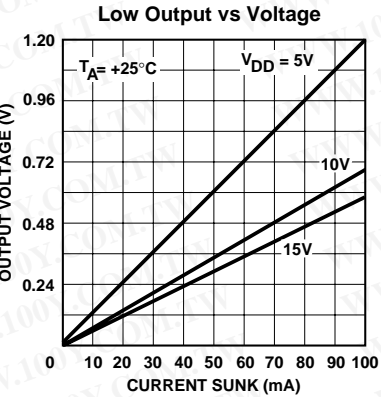
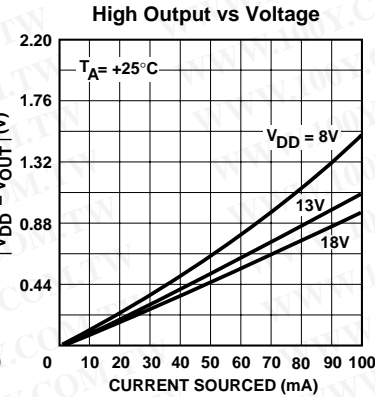
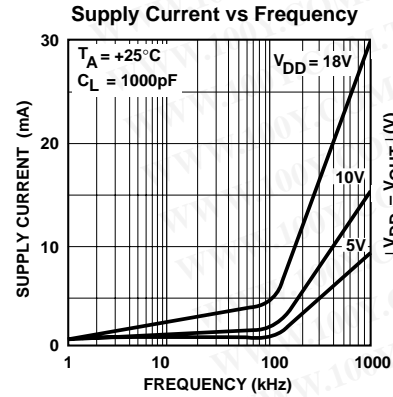
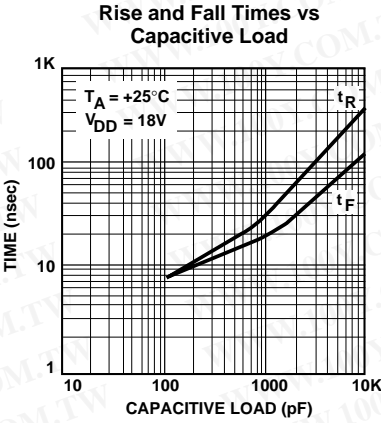
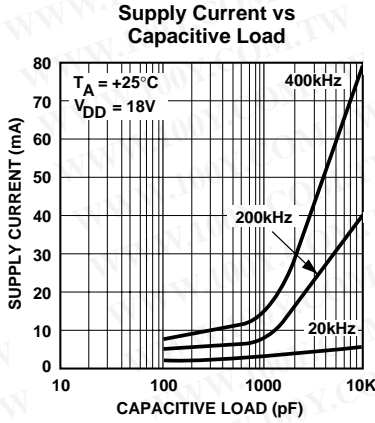
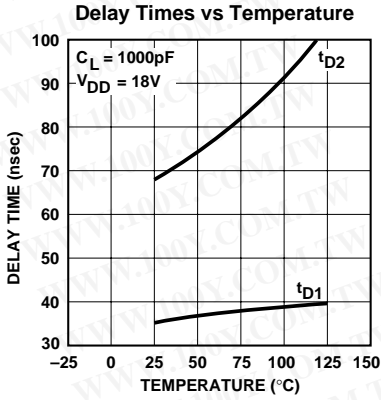
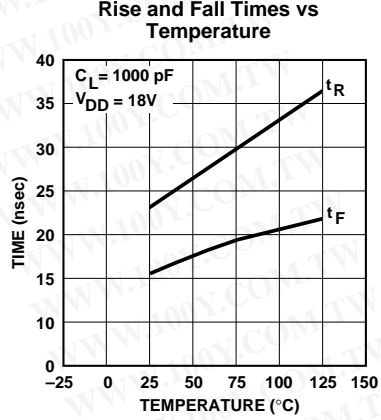
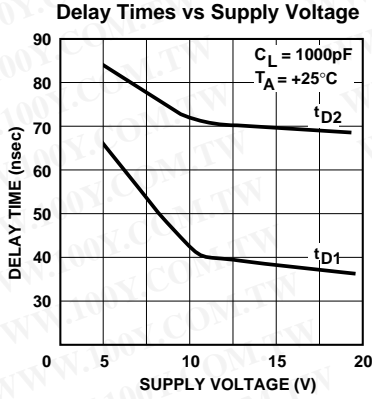
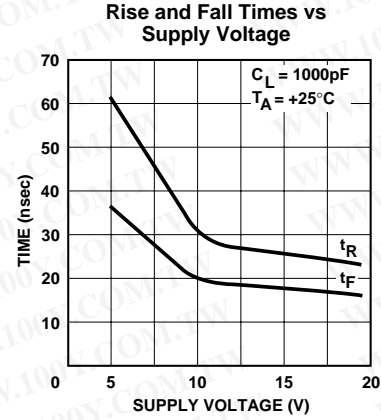
The magnitude of  $P_{AC}$  is readily estimated for several cases:

- |    |                    |    |                    |
|----|--------------------|----|--------------------|
| A. | 1. $f$ = 20kHz     | B. | 1. $f$ = 200kHz    |
|    | 2. $C_L$ = 1000pf  |    | 2. $C_L$ = 1000pf  |
|    | 3. $V_s$ = 18V     |    | 3. $V_s$ = 15V     |
|    | 4. $P_{AC}$ = 65mW |    | 4. $P_{AC}$ = 45mW |

During output level state changes, a current surge will flow through the series connected N and P channel output MOSFETS as one device is turning "ON" while the other is turning "OFF". The current spike flows only during output transitions. The input levels should not be maintained between the logic "0" and logic "1" levels. **Unused driver inputs must be tied to ground and not be allowed to float.** Average power dissipation will be reduced by minimizing input rise times. As shown in the characteristic curves, average supply current is frequency dependent.

TC426  
 TC427  
 TC428

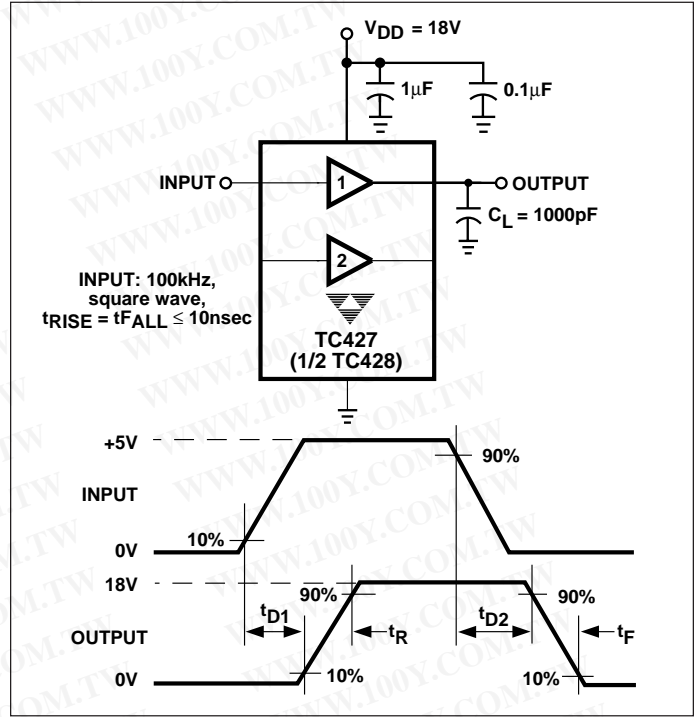
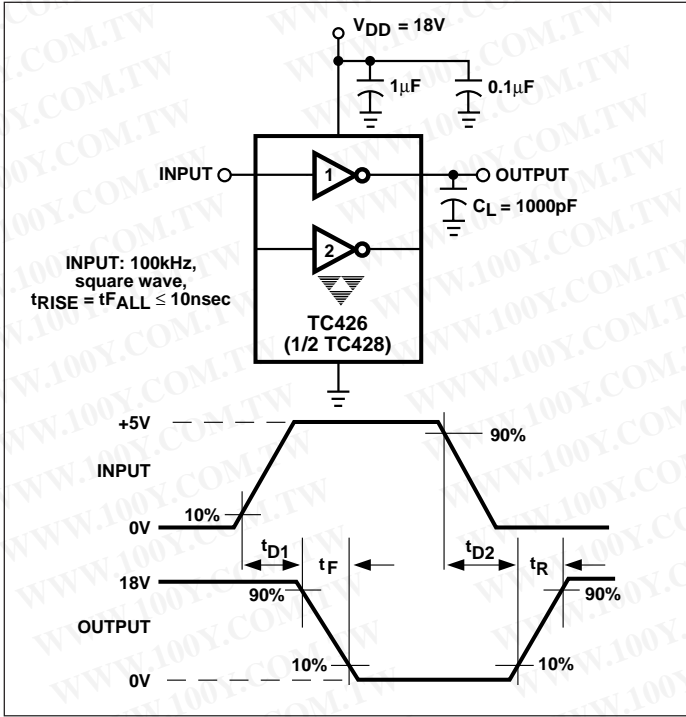
TYPICAL CHARACTERISTICS



# 1.5A DUAL HIGH-SPEED POWER MOSFET DRIVERS

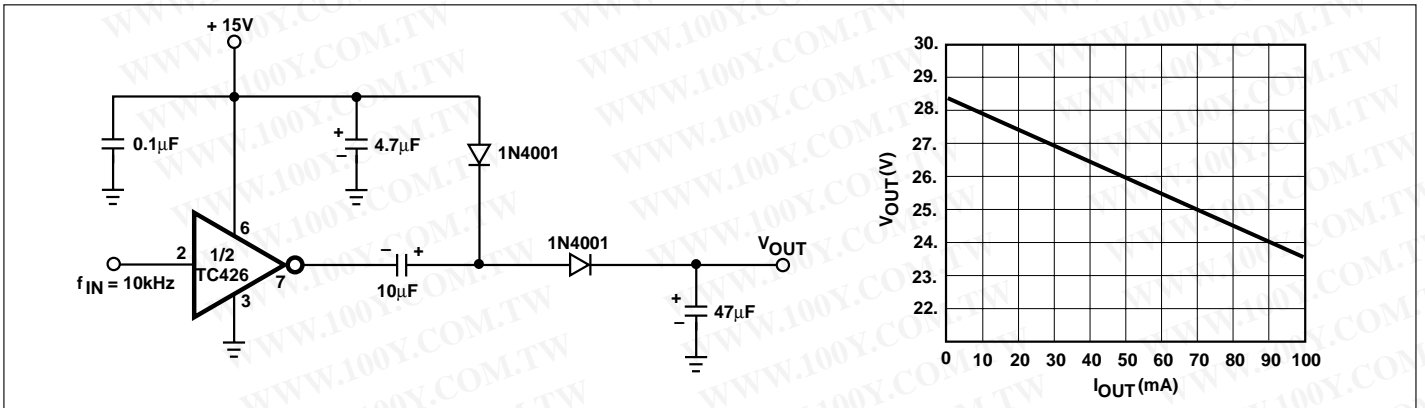
勝特力材料 886-3-5753170  
 勝特力电子(上海) 86-21-54151736  
 勝特力电子(深圳) 86-755-83298787  
[Http://www.100y.com.tw](http://www.100y.com.tw)

**TC426**  
**TC427**  
**TC428**



4

## VOLTAGE DOUBLER



## VOLTAGE INVERTER

